NSN 5961-01-301-6707

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-301-6707 **Inclosure Material:** Plastic **Overall Length:** 4.530 inches **Overall Height:** 2.040 inches **Overall Width:** 1.970 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole Voltage Rating In Volts Per Characteristic: 1600.0 repetitive peak off-state voltage all semiconductor device thyristor and 1600.0 repetitive peak reverse voltage all semiconductor device thyristor and 1700.0 nonrepetitive peak reverse voltage all semiconductor device thyristor and 3.0 gate trigger voltage, instantaneous all semiconductor device thyristor **Current Rating Per Characteristic:** 270.00 amperes collector current, dc of standard range all semiconductor device thyristor and 160.00 amperes collector current, dc all semiconductor device thyristor and 300.00 milliamperes forward current, total rms absolute all semiconductor device thyristor **Terminal Type And Quantity:** 3 screw Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: